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Infinite-layer fluoro-nickelates as d⁹ model materials

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Abstract

We study theoretically the fluoro-nickelate series $ANiF_2$ (A = Li, Na, K, Rb, Cs) in the tetragonal P4/mmm infinite-layer structure. We use density functional theory to determine the structural parameters and the electronic band structure of these unprecedented compounds. Thus, we predict these materials as model d^9 systems where the Ni¹⁺ oxidation is realized and the low-energy physics is exclusively determined by the Ni-3d bands. Fluoro-nickelates of this class thus offer an ideal platform for the study of intriguing physics that emerges out of the special d^9 electronic configuration, notably high-temperature unconventional superconductivity.

1. Introduction

The recent discovery of superconductivity in Sr-doped NdNiO₂ thin films [1] has attracted a remarkable research attention (see e.g. [2-17]). In these infinite-layer nickelates the Ni atom takes a nominal 1 + valence with a 3d⁹ electronic configuration that leads to a $3d_{x^2-y^2}$ band crossing the Fermi level. This configuration is rare in nature. At the same time, it is one of the fingerprints of high- T_c superconducting cuprates. That is, in fact, the basis of an intriguing analogy put forward some time ago [18, 19] that now receives a renewed interest and motivates the search for novel d^9 materials [20–22]. Such an analogy, however, is fundamentally limited—among other factors—by the presence of extra R-atom bands in the RNiO₂ nickelates that also intersect the Fermi level and play a special role [9-13].

Here, we investigate theoretically the novel infinite-layer fluoro-nickelate series $ANiF_2$, with A = Li, Na, K, Rb, Cs (see figure 1). These materials can in principle be synthesized from existing fluoro-perovskite precursors through a topotactic reduction process similar to that used to obtain their oxide counterparts [1, 23–25], using an epitaxial thin-film approach to stabilize their structure [1, 26]. In such a hypothetical ANiF₂ series the Ni atom is combined with monovalent elements so that the Ni¹⁺ oxidation state can be ideally expected. Besides, no extra A-atom band is expected near the Fermi level and a sizable separation between Ni-3d and F-2p bands—that is, a large charge transfer energy—could be anticipated given the fact that F is the most electronegative element. In the following, we report first-principles calculations based of density functional theory (DFT) that confirm these ideal expectations. Specifically, we compute the lattice parameters and the electronic band structure of the $ANiF_2$ series (A = Li, Na, K, Rb, Cs). In addition, we study the effect of external pressure and doping together with the tendency to magnetic order of these new compounds. We illustrate our results using KNiF₂ as reference system and report on the rest of fluoro-nickelates in the appendix.

2. Methods

We performed DFT calculations to study the crystal structure and electronic band structure of the ANiF₂ fluoro-nickelates. We used the VASP code [27] to determine the lattice parameters of these systems in the P4/mmm structure, with the PAW pseudo-potentials [28] and the PBE [29] exchange and correlation functional. A plane-wave cutoff of 960 eV and a Monkhorst-Pack $6 \times 6 \times 6$ mesh with a 0.2 eV smearing was used for the calculations. A test performed on the KNiF₂ with a more accurate mesh showed that the structural parameters were converged within 0.002 Å. The corresponding band structures were computed using the full-potential linear augmented plane-wave (FLAPW) method as implemented in the WIEN2k



Figure 1. Ball-and-stick model of the $ANiF_2$ fluoro-nickelates in the P4/mmm space group (left) and $3d^9$ electronic configuration of the Ni¹⁺ under the corresponding crystal field (right).

Table 1. Calculated lattice parameters of $ANiF_2$ fluoro-nickelates in the tetragonal P4/mmm structure (non-magnetic state), and lowest energy of the Γ -point (optical) and *R*-point phonons. The symbol - indicates that a soft phonon of very low energy is obtained in the calculation.

	LiNiF ₂	NaNiF ₂	KNiF ₂	RbNiF ₂	CsNiF ₂
a (Å)	3.956	4.008	4.040	4.046	4.057
c (Å)	2.815	3.058	3.832	4.224	4.645
$\hbar\omega_{\Gamma}$ (meV)	-	16	16	12	10
$\hbar\omega_R \text{ (meV)}$	-	-	13	10	8

package [30] with the LDA exchange and correlation functional [31]. We choose muffin-tin radii of 2.5 a.u., 2.1 a.u., and 1.7 a.u. for the K (Rb, Cs), Ni, and F atoms respectively and a plane-wave cutoff $R_{mt}K_{max} = 7.0$. The non-magnetic calculations were performed using the primitive (1-formula-unit) cell of the chemical structure and a Monkhorst-Pack mesh of $12 \times 12 \times 13$ *k*-points in the irreducible Brillouin zone. The maximally localized Wannier functions (MLWFs) [32] were calculated by interfacing the WANNIER90 package [33] to WIEN2k using the WIEN2WANNIER code [34].

The magnetic solutions were obtained using $\sqrt{2} \times \sqrt{2} \times 2$ supercells with equivalent *k*-point meshes for the following configurations (see e.g. [35] for the definitions): ferromagnetic (FM), *A*-type antiferromagnetic (AFM) with spins pointing in opposite directions along *c* (AFM order of FM planes), *C*-type AFM with spins pointing in opposite directions in consecutive lines (AFM order of FM chains), *G*-type AFM with nearest-neighboring spins pointing in opposite directions ('full' AFM ordering). In addition we also considered the so-called *E*-type AFM order using an adapted supercell. The effect of charge carrier doping was studied using a charged-cell approach with a compensating background, which has been shown to be as good as the virtual crystal approximation for the reference LaNiO₂ nickelate [8].

3. Results

3.1. Crystal structure

The calculated lattice parameters of the fluoro-nickelate series $ANiF_2$ in the P4/mmm structure are summarized in table 1. The computed *a* parameter is comparable to that of the oxide nickelates (see e.g. [1]). However, there is a substantial change in the *c* parameter as a function of the radius of the monovalent *A* atom across the series. This yields a monotonous increase both in the c/a ratio and in the volume of the unit cell with increasing such a radius. Interestingly the lattice parameters become a < c for Rb and Cs, unlike in the oxide counterparts. This behavior suggests that the binding of *A* atom with the NiF₂ layer is mostly due to the electrostatic interactions rather than to covalent bonding.

Table 1 also summarizes the lowest-energy phonons at Γ and R points calculated in the *P4/mmm* infinite-layer structure. Structural instabilities in the corresponding perovskites can be identified from these phonons [36]. We find rather soft modes for LiNiF₂ and NaNiF₂, which signals the vicinity to a structural quantum critical point in these two systems. This is an interesting possibility whose study, however, is beyond the scope of the present work. In fact, even if such a *P4/mmm* structure may be unstable for some fluoro-nickelates in their bulk form, the calculated structures could be stabilized in thin films by means of epitaxial strain.

3.2. Band structure

Figure 2 shows the band structure of KNiF₂, which is a prototype for the $ANiF_2$ series. The bands associated to the F-2*p* orbitals are well separated from the Ni-3*d* ones by an ionic gap of \sim 3 eV and lie below \sim -5 eV.







This is in sharp contrast to the oxide nickelates and even more to the analog cuprates. In the former such an ionic gap nearly closes, while in the latter O-2p and Cu-3d bands actually overlap. According to this feature, the fluoro-nickelates can provide actual materials in which the Mott insulator limit in the Zaanen-Sawatzky-Allen scheme can be realized in the most ideal way [6].

When it comes to the Ni-3*d* bands, they form a compact set near the Fermi level. Their bandwidth ranges from ~ 2.5 eV to ~ 0.5 eV, and therefore are visibly flatter that in the oxide nickelates. Importantly, the Ni-3*d* bands are well separated from the next set of bands higher in energy, none of which intersect the Fermi level. This higher-energy set is much less localized and consequently its orbital character is more hybrid. According to the DOS, it is mainly associated to K-4*s* and Ni-4*s* orbitals with a non-negligible contribution from the Ni-3*d*_{z²} ones.

Figure 3 shows the Ni-3*d* bands resolved according to their orbital character in more detail. As we see, only the Ni-3*d* bands are relevant for the low-energy physics and the $3d_{x^2-y^2}$ character dominates the crossing with the Fermi level. This is totally in tune with the targeted d^9 configuration of the Ni¹⁺ with the nominally half-filled $3d_{x^2-y^2}$ orbital (see figure 1). However, the crossing with the Fermi level apparently involves two different bands that swap their character and become $3d_{z^2}$ below the Fermi energy at *M* and *A*. This feature traces back to an avoided crossing along the *Z*-*R* direction, which can be best appreciated by inspecting the band structure of the whole ANiF₂ series (figures 3 and A1). In fact, the Fermi surface wraps around *M* at $k_z = 0$ while it wraps around *Z* at $k_z = \pi/c$. Thus, despite its apparent two-dimensional character, the Fermi surface is intrinsically a three-dimensional object. The three-dimensional character of the Fermi surface has also been pointed out for LaNiO₂ [19]. However, to the best of our knowledge, its apparent 'multiband' nature related to the avoided crossing with orbital character exchange has been overlooked so far (even if it can be deduced from figure 3 in [19]). A closely related hybridization of this type has been suggested to play a key role in cuprates [37]. Since this feature emerges in the ANiF₂ fluoro-nickelates in a very clean and prominent way, these systems can indeed be of great help to clarify the actual situation.



Table 2. Structural parameters of $KNiF_2$ as a function of pressure in the tetragonal P4/mmm structure (non-magnetic state).

	0 GPa	5 GPa	10 GPa	20 GPa	
a (Å)	4.040	4.004	3.986	3.957	
c (Å)	3.832	3.491	3.265	2.978	

We also studied the changes in the band structure that can be obtained by the application of hydrostatic pressure (see figure 4). The corresponding lattice parameters are listed in table 2. We see that *a* remains essentially constant while *c* decreases significantly under pressure. This reduction increases the overlap between the $3d_{z^2}$ orbitals of neighbouring Ni atoms, and further yields an enhanced dispersion of the $3d_{z^2}$ band between Γ and *Z* (see figure 4). Beyond that, pressure effectively acts as a sort of hole doping in the sense that it produces a shift upwards of a portion of the bands near the Fermi level. This enhances the d_{z^2} orbital content of the Fermi surface and eventually gives rise to an additional hole pocket at *A* (where the corresponding band is rather flat and therefore can yield a sizable van Hove feature). Interestingly, pressure turns out to be an effective control parameter for tuning the avoided crossing with band-character inversion to the Fermi level.

3.3. Wannier functions

In order to gain further insight into the electronic structure of the fluoro-nickelates and compare them with their oxide counterparts, we determined the Wannier orbitals of KNiF₂ in the non-magnetic state. The reduced dispersion and compact nature of both Ni-3d and F-2p band sets simplifies the calculation of the MLWFs, which requires no disentanglement procedure. We used the lowest eleven bands shown in figure 2 to construct eleven MLWFs. These MLWFs are associated to five Ni-3d and six F-2p orbitals, three for each F atom. The spatial spread of these functions is small (< 1.2Å). The on-site energies and hoppings obtained from the Wannier fits are shown in table 3. Compared to the values computed for LaNiO₂ in [2, 38], we find that there is a swap between $d_{x^2-y^2}$ and $d_{xz/yz}$ on-site energies together with a reduction of difference between the $d_{x^2-y^2}$ and the d_{z^2} ones to 0.1 eV. On the other hand, the difference between the Ni- $d_{x^2-y^2}$ and the F- p_x energies increases to \sim 6 eV. This is much larger than in the case of LaNiO₂ and LaCuO₂ [2], as expected from the enhanced electronegativity of the F. This naturally leads to a more localized $d_{x^2-y^2}$ Wannier function, which will be relevant for the problem of polaron formation. In any case, enhanced electronic correlations be naturally expected due to such an increased localization. The Ni-3d and F-2p hopping parameters are 20% smaller than in LaNiO2, but otherwise their relative strength is similar. This indicates that the overlap between Ni and F centered orbitals is as in the oxide counterparts. Finally, the hopping between neighboring F-centered orbitals are very small, confirming the much more localized nature of the 2p orbitals of F with respect to O.

3.4. Spin-polarized calculations

Next, we performed spin-polarized calculations to investigate the tendency to magnetic order in the fluoro-nickelates. Table 4 summarizes the relative energy of the magnetically ordered states with respect the non-magnetic solution in KNiF₂. The lowest energy is obtained for a *G*-type AFM state with a Ni magnetic moment of 0.87 μ_B . This solution is practically degenerate with a *E*-type AFM one. Given the relatively large difference between the FM magnetization energy and the *G*-type AMF one, this suggests some preference for AFM spin alignments (note that all nearest-neighbouring spins are anti-parallel in the *G*-type AFM state). In any case, these magnetization energies are much larger than the corresponding ones in LaNiO₂. Incidentally,

Table 3. Calculated on-site energies and hoppings for KNiF₂ derived from Ni- and F-centered maximally localized Wannier functions (MLWF). The values associated to the F MLWFs are degenerate and the label $\sigma(\pi)$ indicates 2*p* orbitals with parallel (perpendicular) orientation to the Ni - F bond.

Wannier on-site energies (eV)			
$\overline{d_{xy}}$	-0.84		
d _{xz/yz}	-0.59	$p_x\left(\sigma ight)$	-6.51
$d_{x^2-y^2}$	-0.65	$p_{y}(\pi)$	-5.29
d_{z^2}	-0.75	$p_z(\pi)$	-5.37
Wannier hoppings	(eV)		
$d_{xy} - p_y$	0.61		
$d_{xz} - p_z$	0.64		
$d_{x^2-y^2}$ - p_x	-1.05		

Table 4. Calculated energy difference with respect to the non-magnetic state and Ni magnetic moment for different magnetic configurations in KNiF₂ and different values of hole and electron doping.

undoped	FM	Α	С	Е	G
$\frac{\Delta E \text{ (meV/Ni)}}{\mu_{\text{Ni}} (\mu_B)}$	-17 0.96	-75 0.99	-159 0.84	$-162 \\ 0.90$	-163 0.87
0.2 h ⁺ /Ni					
$\frac{\Delta E \text{ (meV/Ni)}}{\mu_{\text{Ni}} (\mu_B)}$	-54 1.08	-106 1.10	-187 1.03	-169 1.05	$-160 \\ 1.00$
0.2 e ⁻ /Ni					
$\frac{\Delta E \text{ (meV/Ni)}}{\mu_{\text{Ni}} (\mu_B)}$	-	-22 0.81	-70 0.67	-74 0.70	-73 0.69
0.4 e ⁻ /Ni					
$\frac{\Delta E \text{ (meV/Ni)}}{\mu_{\text{Ni}} (\mu_B)}$	-	>-1 0.11	-23 0.52	$-41 \\ 0.50$	-24 0.53



we note that such an enhanced tendency to magnetic order yields an insulating *G*-type AFM state with remarkably flat bands just below the Fermi energy (see figure 5).

Hydrostatic pressure does not have a dramatic influence on the *G*-type AFM state. Its magnetization energy becomes -150, -138 and -112 meV/Ni at 5, 10 and 20 GPa respectively in our calculations. At the same time, the magnetisation energy of the FM state is -14 meV/Ni at 20 GPa. These trends suggest that pressure is moderately effective in suppressing the tendency to magnetism in KNiF₂. This should not be very surprising since the Ni-3*d* electrons are very localized in the *G*-type AFM state, as can be seen from the rather flat valence bands that are obtained in that case (see figure 5).



Finally, we also studied the influence of charge carrier doping on the tendency to magnetism of KNiF₂. The results are summarized in table 4. We find that hole doping makes the magnetic solutions even more stable. This could be anticipated for the FM state from the corresponding increase in the DOS at the Fermi level (see e.g. [39]). In fact, hole doping favors the parallel alignment of the spins with respect to the anti-parallel one. Specifically, all the orders displaying FM nearest-neighbouring spins are favored while the G-type AFM order, in which all these spins are AFM, is slightly suppressed. At the same time, hole doping can render the system metallic again as illustrated in figure A2. However, due to the flatness of the bands crossing the Fermi level, this can yield additional instabilities and/or enhance the role of electronic correlations thereby modifying substantially the DFT picture. Electron doping has a reverse and much stronger influence on the magnetism. In this case, all the magnetic solutions tend to be suppressed. The FM one, in particular, is already absent at 0.2 e⁻/Ni while the rest of configurations become nearly degenerate in energy. A further increase to 0.4 e⁻/Ni eventually favors the *E*-type AFM state over the *G*-type one. We note that these magnetic states also become metallic due to electron doping (see figure A2). There is however an asymmetry between hole and electron doping due to the splitting bands. This is such that the bands crossing the Fermi level in the eletron-doped case still display an important dispersion, by virtue of which this DFT picture can be expected to be more reliable. In any case, this reveals an intriguing magnetic softness, and suggests that electron doping can be used as a control parameter to tune and eventually suppress the tendency to magnetism in the fluoro-nickelates.

4. Discussion

Our results demonstrate that the infinite-layer fluoro-nickelates ANiF₂ can serve as model materials for the study of the physics associated to the d^9 electronic configuration. This special configuration emerges in these systems in a very clean and ideal way. Namely, the Ni-3d bands are remarkably decoupled from the rest and determine completely the low-energy electronic properties of these systems. In this sense, we anticipate similar features for A = Mg, Ca, and Sr. What are the overall physical properties that emerge from such a textbook situation is a very interesting question in itself. In addition, the experimental realization of these compounds will offer an unprecedented playground to test, in particular, some important ideas that have been put forward in relation to the material dependence of the superconducting T_c in the cuprates. On one hand, the fluoro-nickelates ANiF₂ naturally display a much larger charge-transfer energy compared to copper and nickel oxide counterparts. Consequently, electronic correlations can be expected to transform these systems into ideal Mott insulators—rather than charge-transfer insulators—which is believed to have a tight link to T_c in cuprates. This link, however, is somehow challenged by the superconducting nickelates, which can therefore be further examined in fluoro-nickelate materials. On the other hand, at the DFT level, the fluoro-nickelates $ANiF_2$ display a Fermi surface whose topology matches that of the superconducting cuprates and is equally dominated by $d_{x^2-y^2}$ orbital contributions. At the same time, these orbitals display an intriguing interplay with the d_{z^2} ones that is important for the overall band-structure picture and the eventual Cooper pairing. In fact, this interplay emerges in the fluoro-nickelates in the most ideal and neat way, and it can be tuned across the ANiF2 series as well as by means of pressure or charge doping. Such an interplay has also been linked to the superconducting T_c [37], so that the fluoro-nickelates can be of great help to further elucidate this point. Thus, we expect that our findings will motivate further experimental work focused on novel fluoro-nickelates as well as the search for additional d^9 materials.



Figure A2. Fatband plot of the electronic band structure of the *G*-AFM and *C*-AFM states in $KNiF_2$ as a function of doping. The reordering of the split bands introduces an asymmetry between hole and electron doping. The metallic character of these AFM states implies flat bands at the Fermi level in hole-doped case (left), while they still display a relatively important dispersion in the electron-doped case (right).

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